# Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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# 2SK3154

# Silicon N Channel MOS FET High Speed Power Switching

REJ03G1079-0300

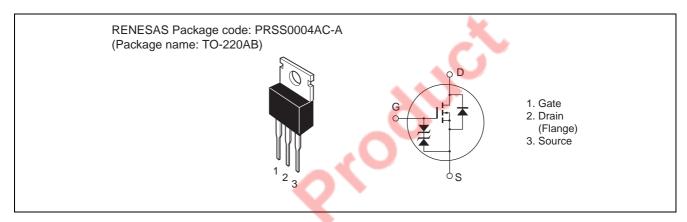
(Previous: ADE-208-682A)

Rev.3.00 Sep 07, 2005

#### **Features**

- Low on-resistance  $R_{DS} = 100 \text{ m}\Omega$  typ.
- High speed switching
- 4 V gate drive device can be driven from 5 V source

### **Outline**



# **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	150	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	15	А
Drain peak current	I <sub>D(pulse)</sub> Note1	60	A
Body-drain diode reverse drain current	I <sub>DR</sub>	15	А
Avalanche current	I <sub>AP</sub> Note3	15	А
Avalanche energy	E <sub>AR</sub> Note3	16	mJ
Channel dissipation	Pch Note2	50	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1 %

2. Value at  $Tc = 25^{\circ}C$ 

3. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

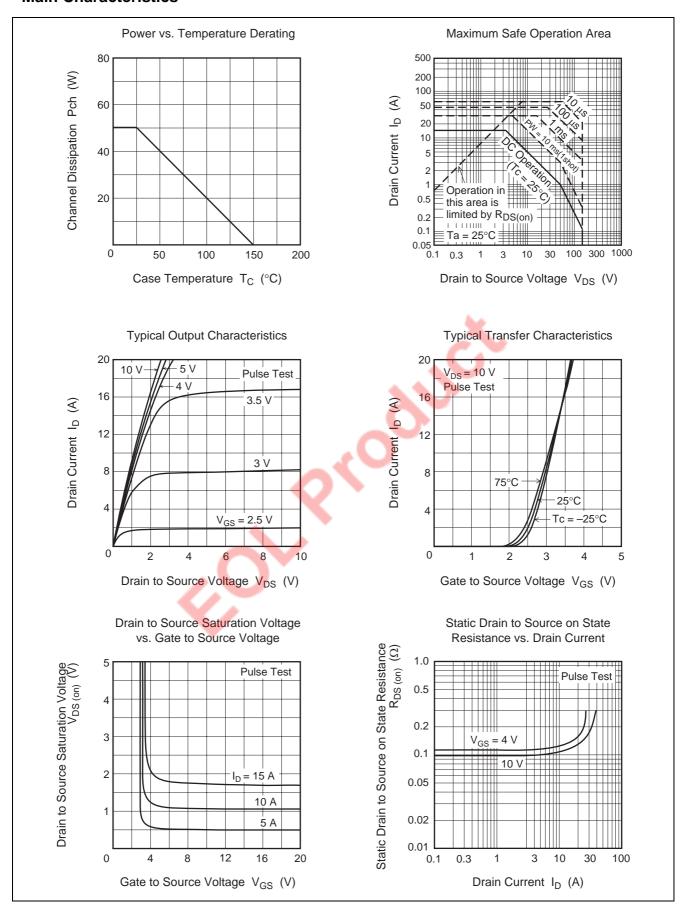
## **Electrical Characteristics**

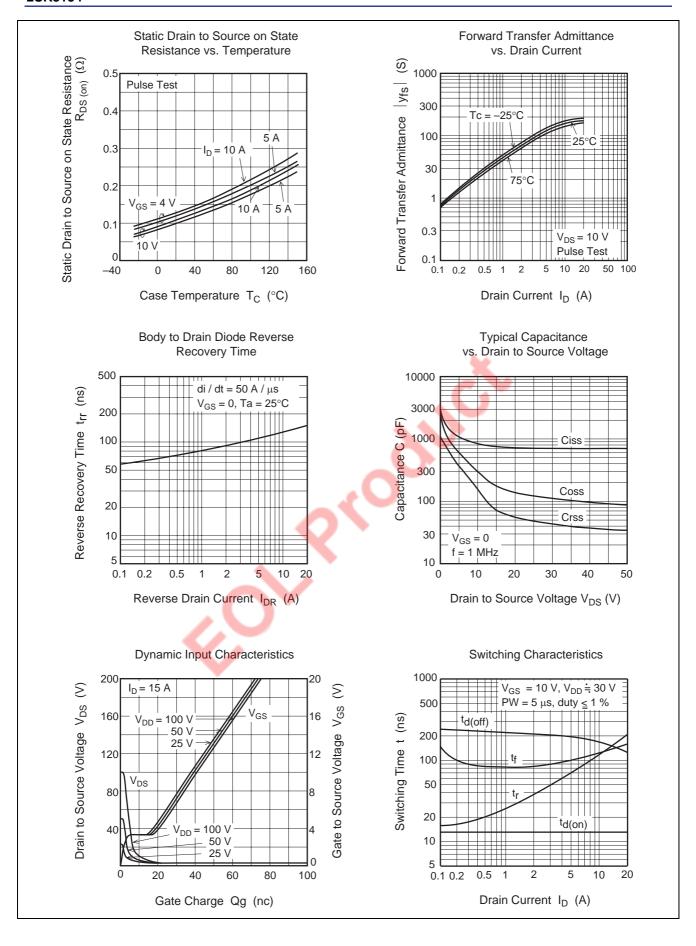
 $(Ta = 25^{\circ}C)$ 

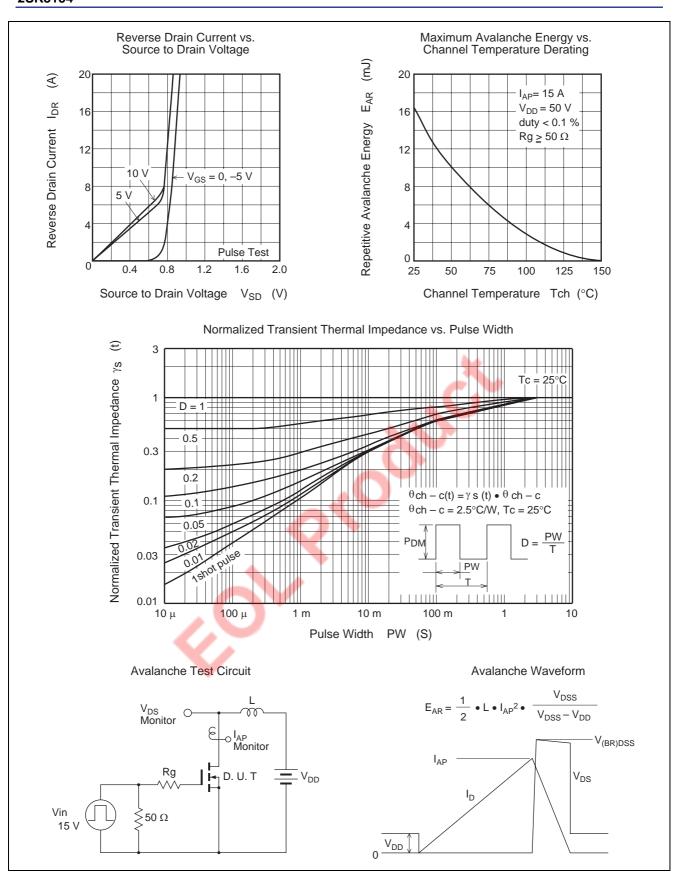
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	150	_		V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V <sub>(BR)GSS</sub>	±20	_	1-1	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	10	μΑ	$V_{DS} = 150 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	4	2.5	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state	R <sub>DS(on)</sub>	_	0.10	0.13	Ω	$I_D = 8 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
resistance	R <sub>DS(on)</sub>	(-)	0.12	0.15	Ω	$I_D = 8 \text{ A}, V_{GS} = 4 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y <sub>fs</sub>	8.5	14	_	S	$I_D = 8 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	850	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	-	300	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	<u> </u>	160	_	pF	
Turn-on delay time	t <sub>d(on)</sub>	_	13	_	ns	$I_D = 8 \text{ A}, V_{GS} = 10 \text{ V},$
Rise time	t <sub>r</sub>	_	100	_	ns	$R_L = 3.75 \Omega$
Turn-off delay time	t <sub>d(off)</sub>	_	195	_	ns	
Fall time	t <sub>f</sub>	_	110	_	ns	
Body-drain diode forward voltage	$V_{DF}$	_	0.9	_	V	I <sub>F</sub> = 15 A, V <sub>GS</sub> = 0
Body-drain diode reverse recovery	t <sub>rr</sub>	_	140	_	ns	I <sub>F</sub> = 15 A, V <sub>GS</sub> = 0
time						$di_F/dt = 50 \text{ A/} \mu\text{s}$

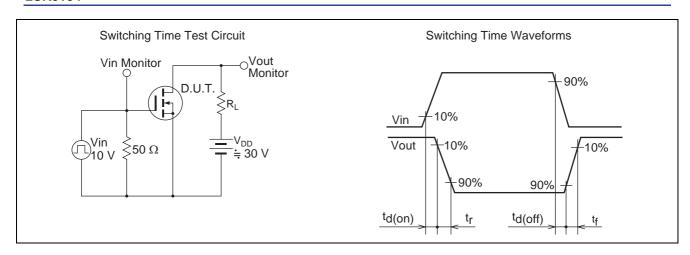
Note: 4. Pulse test

#### **Main Characteristics**



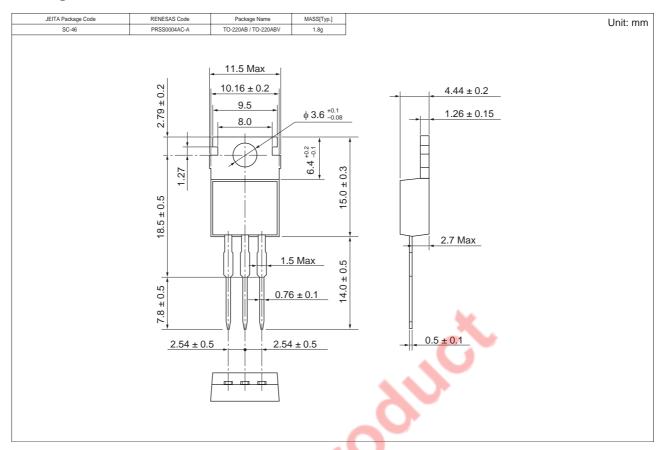








# **Package Dimensions**



# **Ordering Information**

Part Name	Quantity	Shipping Container		
2SK3154-E	500 pcs	Box (Sack)		

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